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Amendments to the Claims

This listing of claims replaces all prior versions and listings of claims in the application.

Listing of Claims

1-16. (Canceled)

17. (Currently Amended) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode of a protective capacitor over the substrate, ~~for forming a protective capacitor~~, wherein the third electrode surrounds the active matrix circuit region and the driver circuit region; ~~and wherein the first through the third electrodes are electrically connected with each other; and~~
performing at least one step with the third electrode being electrically connected to the first and the second electrodes; and
electrically separating the third electrode from the first and the second electrodes after performing said at least one step.

18. (Previously Presented) A method for manufacturing a display device according to claim 17, wherein the first through the third electrodes comprise aluminum.

19. (Canceled)

20. (Previously Presented) A method for manufacturing a display device according to claim 17, wherein the display device is a liquid crystal display device.

21. (Currently Amended) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;

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forming a second electrode in a driver circuit region over the substrate;
forming a third electrode over the substrate, wherein the third electrode surrounds the active matrix circuit region and the driver circuit region, wherein the first through the third electrodes are on a same layer; ~~and wherein the first through the third electrodes are electrically connected with each other; and~~
performing at least one step with the third electrode being electrically connected to the first and the second electrodes; and
electrically separating the third electrode from the first and the second electrodes after performing said at least one step.

22. (Previously Presented) A method for manufacturing a display device according to claim 21, wherein the first through the third electrodes comprise aluminum.

23. (Currently Amended) A method for manufacturing a display device according to claim 21, wherein the third electrode is an electrode of for forming a protective capacitor.

24. (Previously Presented) A method for manufacturing a display device according to claim 21, wherein the display device is a liquid crystal display device.

25. (Currently Amended) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode over the substrate, wherein the third electrode surrounds the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes; ~~and wherein the first through the third electrodes are electrically connected with each other; and~~
performing at least one step with the third electrode being electrically connected to the first and the second electrodes; and

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electrically separating the third electrode from the first and the second electrodes after performing said at least one step.

26. (Previously Presented) A method for manufacturing a display device according to claim 25, wherein the first through the third electrodes comprise aluminum.

27. (Currently Amended) A method for manufacturing a display device according to claim 25, wherein the third electrode is an electrode of for forming a protective capacitor.

28. (Previously Presented) A method for manufacturing a display device according to claim 25, wherein the display device is a liquid crystal display device.

29. (Currently Amended) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region, over the substrate;
forming a third electrode over the substrate, wherein the third electrode is located outside the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes; ~~and wherein the first through the third electrodes are electrically connected with each other; and~~

performing at least one step with the third electrode being electrically connected to the first and the second electrodes; and

electrically separating the third electrode from the first and the second electrodes after performing said at least one step.

30. (Previously Presented) A method for manufacturing a display device according to claim 29, wherein the display device is a liquid crystal display device.

31. (Currently Amended) A method for manufacturing a display device comprising:

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forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode of a protective capacitor over the substrate ~~for forming a protective capacitor~~, wherein the third electrode is located outside the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes; ~~and wherein the first through the third electrodes are electrically connected with each other; and~~
performing at least one step with the third electrode being electrically connected to the first and the second electrodes; and
electrically separating the third electrode from the first and the second electrodes after performing said at least one step.

32. (Previously Presented) A method for manufacturing a display device according to claim 31, wherein the display device is a liquid crystal display device.

33. (Currently Amended) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode over the substrate, wherein the third electrode is located outside the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes, and wherein the first through the third electrodes comprise aluminum; ~~and are electrically connected with each other; and~~
performing at least one step with the third electrode being electrically connected to the first and the second electrodes; and
electrically separating the third electrode from the first and the second electrodes after performing said at least one step.

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34. (Previously Presented) A method for manufacturing a display device according to claim 33, wherein the display device is a liquid crystal display device.

35. (Currently Amended) A method for manufacturing a display device comprising:
forming a first electrode in an active matrix circuit region over a substrate;
forming a second electrode in a driver circuit region over the substrate;
forming a third electrode of a protective capacitor over the substrate ~~for forming a protective capacitor~~, wherein the third electrode is located outside the active matrix circuit region and the driver circuit region, wherein the third electrode has a larger width than that of the first and the second electrodes, and wherein the first through the third electrodes comprise aluminum; ~~and are electrically connected with each other; and~~
performing at least one step with the third electrode being electrically connected to the first and the second electrodes; and
electrically separating the third electrode from the first and the second electrodes after performing said at least one step.

36. (Previously Presented) A method for manufacturing a display device according to claim 35, wherein the display device is a liquid crystal display device.

37. (Currently Amended) A method for manufacturing a display device comprising:
forming at least two first conductive layers in an active matrix circuit region over a substrate;
forming a second conductive layer over the substrate, wherein the second conductive layer ~~is electrically connected to the two first conductive layers and~~ is located between the active matrix circuit region and an edge of the substrate;
performing at least one step with the second conductive layer being electrically connected to the two first conductive layers; and

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electrically separating the second conductive layer from the two first conductive layers
after performing said at least one step, and

wherein the second conductive layer is an electrode of a protective capacitor ~~forms a protective capacitor using the second conductive layer as an electrode.~~

38. (Previously Presented) A method for manufacturing a display device according to claim 37, wherein the two first conductive layers are a gate line and a source line.

39. (Previously Presented) A method for manufacturing a display device according to claim 37, wherein the second conductive layer surrounds the active matrix circuit region.

40. (Previously Presented) A method for manufacturing a display device according to claim 37, wherein the display device further comprising a third conductive layer in a driver circuit region over the substrate.

41. (Currently Amended) A method for manufacturing a display device according to claim 37, wherein the protective capacitor comprises ~~another electrode which comprises a~~ semiconductor layer as an electrode.

42. (Previously Presented) A method for manufacturing a display device according to claim 37, wherein the first and the second conductive layers comprise aluminum.

43. (New) A method for manufacturing a display device according to claim 17, wherein said at least one step comprises forming a thin film by a plasma CVD method.

44. (New) A method for manufacturing a display device according to claim 17, wherein said at least one step comprises etching a film by plasma etching.

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45. (New) A method for manufacturing a display device according to claim 17, wherein said at least one step comprises a rubbing step.

46. (New) A method for manufacturing a display device according to claim 17, wherein said at least one step comprises forming an insulating layer over the first to third electrode, the method further comprising etching the insulating layer in the active matrix circuit region and the driver circuit region.

47. (New) A method for manufacturing a display device according to claim 21, wherein said at least one step comprises forming a thin film by a plasma CVD method.

48. (New) A method for manufacturing a display device according to claim 21, wherein said at least one step comprises etching a film by plasma etching.

49. (New) A method for manufacturing a display device according to claim 21, wherein said at least one step comprises rubbing step.

50. (New) A method for manufacturing a display device according to claim 21, wherein said at least one step comprises forming an insulating layer over the first to third electrode, the method further comprising etching the insulating layer in the active matrix circuit region and the driver circuit region.

51. (New) A method for manufacturing a display device according to claim 25, wherein said at least one step comprises forming a thin film by a plasma CVD method.

52. (New) A method for manufacturing a display device according to claim 25, wherein said at least one step comprises etching a film by plasma etching.

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53. (New) A method for manufacturing a display device according to claim 25, wherein said at least one step comprises a rubbing step.

54. (New) A method for manufacturing a display device according to claim 25, wherein said at least one step comprises forming an insulating layer over the first to third electrodes, the method further comprising etching the insulating layer in the active matrix circuit region and the driver circuit region.

55. (New) A method for manufacturing a display device according to claim 29, wherein said at least one step comprises forming a thin film by a plasma CVD method.

56. (New) A method for manufacturing a display device according to claim 29, wherein said at least one step comprises etching a film by plasma etching.

57. (New) A method for manufacturing a display device according to claim 29, wherein said at least one step comprises a rubbing step.

58. (New) A method for manufacturing a display device according to claim 29, wherein said at least one step comprises forming an insulating layer over the first to third electrode, the method further comprising etching the insulating layer in the active matrix circuit region and the driver circuit region.

59. (New) A method for manufacturing a display device according to claim 31, wherein said at least one step comprises forming a thin film by a plasma CVD method.

60. (New) A method for manufacturing a display device according to claim 31, wherein said at least one step comprises etching a film by plasma etching.

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61. (New) A method for manufacturing a display device according to claim 31, wherein said at least one step comprises a rubbing step.

62. (New) A method for manufacturing a display device according to claim 31, wherein said at least one step comprises forming an insulating layer over the first to third electrodes, the method further comprising etching the insulating layer in the active matrix circuit region and the driver circuit region.

63. (New) A method for manufacturing a display device according to claim 33, wherein said at least one step comprises forming a thin film by a plasma CVD method.

64. (New) A method for manufacturing a display device according to claim 33, wherein said at least one step comprises etching a film by plasma etching.

65. (New) A method for manufacturing a display device according to claim 33, wherein said at least one step comprises a rubbing step.

66. (New) A method for manufacturing a display device according to claim 33, wherein said at least one step comprises forming an insulating layer over the first to third electrodes, the method further comprising etching the insulating layer in the active matrix circuit region and the driver circuit region.

67. (New) A method for manufacturing a display device according to claim 35, wherein said at least one step comprises forming a thin film by a plasma CVD method.

68. (New) A method for manufacturing a display device according to claim 35, wherein said at least one step comprises etching a film by plasma etching.

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69. (New) A method for manufacturing a display device according to claim 35, wherein said at least one step comprises a rubbing step.

70. (New) A method for manufacturing a display device according to claim 35, wherein said at least one step comprises forming an insulating layer over the first to third electrodes, the method further comprising etching the insulating layer in the active matrix circuit region and the driver circuit region.

71. (New) A method for manufacturing a display device according to claim 37, wherein said at least one step comprises forming a thin film by a plasma CVD method.

72. (New) A method for manufacturing a display device according to claim 37, wherein said at least one step comprises etching a film by plasma etching.

73. (New) A method for manufacturing a display device according to claim 37, wherein said at least one step comprises a rubbing step.

74. (New) A method for manufacturing a display device according to claim 37, wherein said at least one step comprises forming an insulating layer over the first to third electrode, the method further comprising etching the insulating layer in the active matrix circuit region and the driver circuit region.